

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:

Yi Ding

Assignee:

ProMOS Technologies, Inc.

Title:

Arrays of Nonvolatile Memory Cells Wherein Each Cell Has Two

Conductive Floating Gates

Application No.:

10/632,007

Filing Date:

July 30, 2003

Examiner:

Ida M. Soward

Group Art Unit:

.

Docket No.:

M-15223 US

San Jose, California November 2, 2004

Mail Stop Issue Fee Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

## **INFORMATION DISCLOSURE STATEMENT UNDER 37 CFR § 1.56**

Dear Sir:

Pursuant to 37 CFR § 1.56, § 1.97 and § 1.98, the documents listed on the accompanying form PTO-1449 are called to the attention of the Examiner for the above patent application. Copies of these documents are not enclosed.

Citation of these documents shall not be construed as:

- 1. an admission that the documents are necessarily prior art with respect to the instant invention;
  - 2. a representation that a search has been made, other than as described above; or
- 3. an admission that the information cited herein is, or is considered to be material to patentability as defined in § 1.56(b).

If a fee is required for this Information Disclosure Statement, please charge it to DepositiAccount No. 50-2257. This form is being submitted in duplicate.

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LAW OFFICES OF MacPherson, Kunh, Chen & Held LLP 752 Tuchnology Drive, Saise 225 San Iver, CA 95110 Telephone (403) 392-9520 Fan (408) 392-9522 Il hereby certify that this correspondence is being deposited with the United States Postal Service as First Class Mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on November 2, 2004.

Attorney for Applicant

Date of Signature

Respectfully submitted,

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Serial No. 10/632,007

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